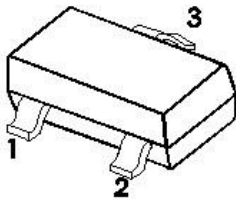


SOT-23

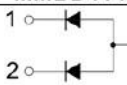
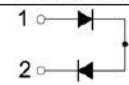


特征 Features

- 开关速度小于 4.0nS; Fast Switching Device (TRR <4.0 nS)
- 最大功率耗散 350mW; Power Dissipation of 350mW
- 高稳定性和可靠性。High Stability and High Reliability
- 反向漏电流小。Low reverse leakage

机械数据 Mechanical Data

- 封装: SOT-23 封装 SOT-23 Small Outline Plastic Package
- 环氧树脂 UL 易燃等级 Epoxy UL: 94V-0
- 安装位置: 任意 Mounting Position: Any

MMBD4148A	MMBD4148CA	MMBD4148CC	MMBD4148SE
			
MARKING:5H	MARKING:D6	MARKING:D5	MARKING:D4

极限值和温度特性(TA = 25°C 除非另有规定)

Maximum Ratings & Thermal Characteristics (Ratings at 25°C ambient temperature unless otherwise specified.)

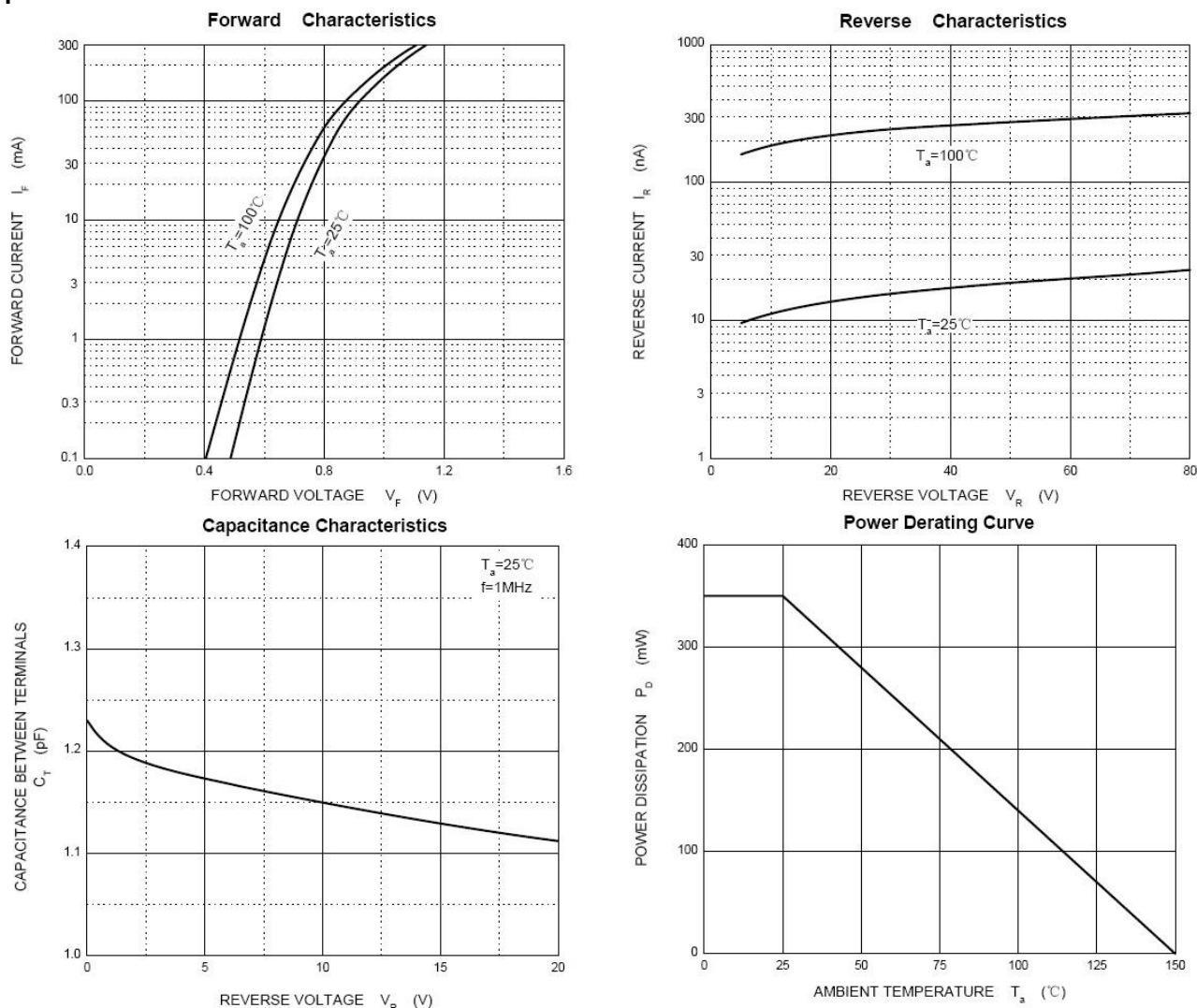
参数 Parameters	符号 Symbol	数值 Value	单位 Unit
反向电压 Reverse Voltage	V _R	75	V
反向峰值电压 Peak Repetitive Reverse Voltage	V _{RRM}	100	V
功率消耗 Power Dissipation	P _d	350	mW
平均整流电流 Average Rectified Current	I _o	200	mA
正向(不重复)浪涌电流 Non-Repetitive Peak Forward Surge Current @t=8.3ms; TA=25°C	I _{FSM}	2.0	A
工作结温 Operating junction temperature	T _j	150	°C
存储温度 Storage temperature range	T _s	-55-+150	°C
热阻抗 Thermal Resistance from Junction to Ambient	R _{θJA}	357	°C/W

Valid provided that electrodes are kept at ambient temperature.

电特性 Electrical Characteristics (Ratings at 25°C ambient temperature unless otherwise specified).

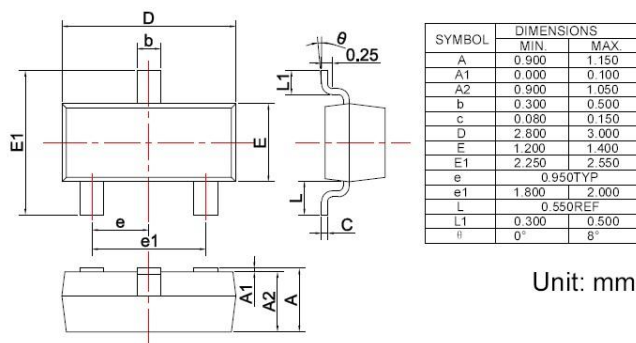
符号 Symbols	参数 Parameter	测试条件 Test Condition	界限 Limits		单位 Unit
			Min	Max	
V(BR)	反向电压 Reverse Voltage	IR=100uA	75		V
IR	反向漏电流 Reverse Leakage Current	VR=75V	—	5.0	uA
		VR=25V	—	25	nA
V _F	正向电压 Forward Voltage	IF=10mA	—	1.00	V
TRR	反向恢复时间 Reverse Recovery Time	IF= IR=10mA	—	4	nS
		VR=6V, RL=100Ω			
		IRR=0.1 X IR			
CT	结电容 Capacitance	VR=0V, f=1MHZ	—	4	pF

Typical Characteristics

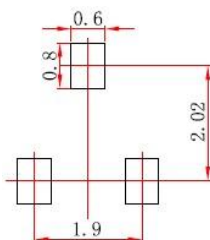


SOT-23 PACKAGE OUTLINE

Plastic surface mounted package



焊盘设计参考 Precautions: PCB Design (Recommended land dimensions for SOT-23 diode. Electrode patterns for PCBs)



Note:
 1. Controlling dimension: In millimeters.
 2. General tolerance: $\pm 0.05\text{mm}$.
 3. The pad layout is for reference purposes only.